

HD74LS221

Dual Monostable Multivibrators

REJ03D0458-0300 Rev.3.00 Jul.15.2005

This multivibrator features a negative-transition-triggered input and a positive-transition-triggered input either of which can be used as an inhibit input. Pulse triggering occurs at a particular voltage level and is not directly related to the transition time of the input pulse. Schmitt-trigger input circuitry (TTL hysteresis) for B input allows jitter-free triggering from inputs with transition rates as slow as 1 V/s, providing the circuit with excellent noise immunity of typically 1.2 V. A high immunity to V_{CC} noise of typically 1.5 V is also provided by internal latching circuitry. Once fired, the outputs are independent of further transitions of the A and B inputs and are a function of the timing components, or the output pulses can be terminated by the overriding clear. Input pulses may be of any duration relative to the output pulse. Output rise and fall times are TTL compatible and independent of pulse length.

Typical triggering and clearing sequence are illustrated as a part of the switching characteristics waveforms. Pulse width stability is achieved through internal compensation and is virtually independent of V_{CC} and temperature.

In most applications, pulse stability will only be limited by the accuracy of external timing components. Jitter-free operation is maintained over the full temperature and V_{CC} range for more than six decades of timing capacitance (10 pF to $10 \, \mu F$) and more than one decade of timing resistance (2 k Ω to $100 \, k\Omega$).

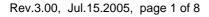
Throughout these ranges, pulse width is defined by the relationship: $t_{w \text{ (out)}} = \text{Cext} \bullet \text{Rext} \bullet \text{1n 2}$.

Features

• Ordering Information

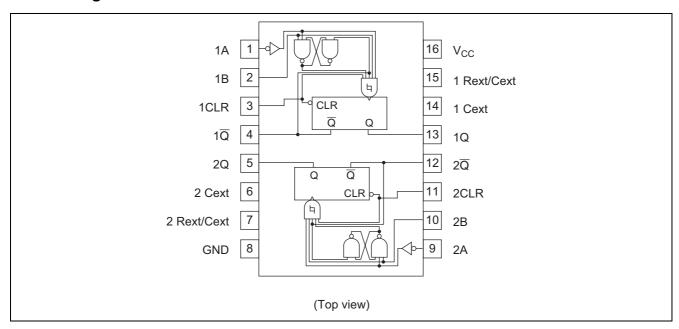
Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LS221P	DILP-16 pin	PRDP0016AE-B (DP-16FV)	Р	_
HD74LS221RPEL	SOP-16 pin (JEDEC)	PRSP0016DG-A (FP-16DNV)	RP	EL (2,500 pcs/reel)

Note: Please consult the sales office for the above package availability.





Pin Arrangement



Function Table

	Inputs	Outputs		
Clear	Α	В	Q	Q
L	X	X	L	Н
Х	Н	X	L	Н
Х	X	L	L	Н
Н	L	1	Л	ъ
Н	\	Н	Л	ъ
↑	L	Н	Л	ъ

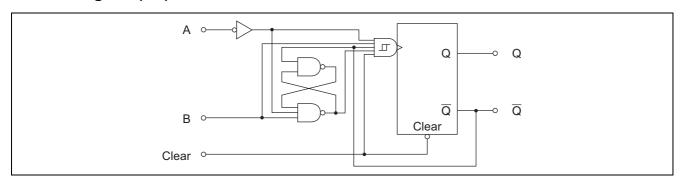
Notes: H; high level, L; low level, X; irrelevant.

↓; Transition from high to low level.

↑; Transition from low to high level.

 $\ \square$; one high-level pulse. $\ \square$; one low-level pulse.

Block Diagram (1/2)



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage	V _{CC}	7	V
Input voltage	V _{IN}	7	V
Power dissipation	P _T	400	mW
Storage temperature	Tstg	-65 to +150	°C

Note: Voltage value, unless otherwise noted, are with respect to network ground terminal.

Recommended Operating Conditions

Item	ı	Symbol	Min	Тур	Max	Unit
Supply voltage		V_{CC}	4.75	5.00	5.25	V
Output ourrent		I _{OH}	_	_	-400	μΑ
Output current		I _{OL}	_	_	8	mA
Operating temperature	Э	T_{opr}	-20	25	75	°C
Rate of rise or fall of	Schmitt input, B	dV/dt	1	_	_	V/s
input pulse	Logic Input, A	u v/ut	1	_	_	V/μs
Input pulso width	A or B	t _{w (in)}	40	_	_	no
Input pulse width	Clear	t _{w (clear)}	40	_	_	ns
Setup time		t _{su}	15	_	_	ns
External timing resistance		R _{ext}	1.4	_	100	kΩ
External timing capacitance		C _{ext}	0	_	1000	μF
Duty cycle	$R_T = 2 k\Omega$		_	_	50	
	R _T = 100 kΩ		_	_	90	

Electrical Characteristics

 $(Ta = -20 \text{ to } +75 \text{ }^{\circ}\text{C})$

Item		Symbol	min.	typ.*	max.	Unit	Condition	
	Α	V_T^+		1.0	2.0	V	V _{CC} = 4.75 V	
Threshold	A	V_T^-	0.8	1.0		٧	V _{CC} = 4.75 V	
voltage	В	V_T^+		1.0	2.0	٧	V _{CC} = 4.75 V	
	Ь	V_T^-	0.8	0.9		٧	V _{CC} = 4.75 V	
		V_{OH}	2.7			٧	$V_{CC} = 4.75 \text{ V}, I_{OH} = -400 \mu\text{A}$	
Output voltage		V_{OL}			0.4	V	$I_{OL} = 4 \text{ mA}$ $I_{OL} = 8 \text{ mA}$ $V_{CC} = 4.75 \text{ V}$	
					0.5	V	$I_{OL} = 8 \text{ mA}$ $VCC = 4.73 \text{ V}$	
		I _{IH}			20	μΑ	$V_{CC} = 5.25 \text{ V}, V_{I} = 2.7 \text{ V}$	
Input current	Α	I _{IL}			-0.4	mA	V _{CC} = 5.25 V, V _I = 0.4 V	
Input current	B, Clear	IIL			-0.8	ША		
		-			0.1	mA	$V_{CC} = 5.25 \text{ V}, V_{I} = 7 \text{ V}$	
Short-circuit ou current	ıtput	I _{OS}	-20	-	-100	mA	V _{CC} = 5.25 V	
Supply current		I _{CC}		4.7	11	mA	Ouiescent V _{CC} = 5.25 V	
		ICC		19	27	IIIA	Triggered VCC = 5.25 V	
Input clamp voltage		V_{IK}	_	_	-1.5	V	$V_{CC} = 4.75 \text{ V}, I_{IN} = -18 \text{ mA}$	

Note: * V_{CC} = 5 V, Ta = 25°C

Switching Characteristics

 $(V_{CC} = 5 \text{ V}, \text{Ta} = 25^{\circ}\text{C})$

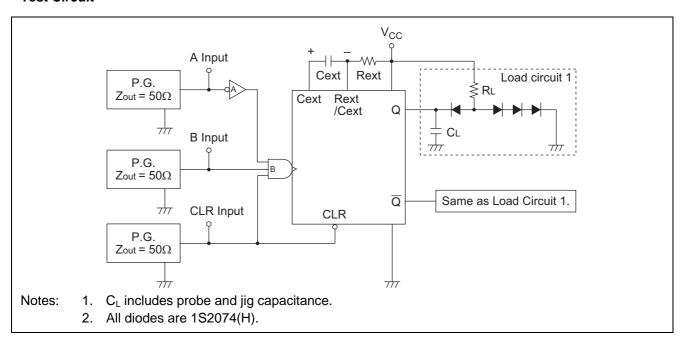
Item	Symbol	Inputs	Outputs	min.	typ.	max.	Unit	Condi	tion
	t _{PLH}	Α	Q	_	45	70	20		
		В	Q	_	35	55	ns		
Propagation	4	Α	Q	_	50	80	no	$C_{\text{ext}} = 80 \text{ pF},$	
delay time	t _{PHL}	В	Q	_	40	65	ns	$R_{ext} = 2 k\Omega$	
	t _{PHL}	Clear	Q	_	35	55	ns		$C_L = 15 \text{ pF},$ $R_L = 2 \text{ k}\Omega$
	t _{PLH}	Clear	Q	_	44	65	ns		
	t _{w (out)}	$t_{w (out)}$ A or B Q or $\overline{\mathbb{Q}}$ —		70	120	150	ns	$C_{\text{ext}} = 80 \text{ pF},$	
								$R_{\text{ext}} = 2 \text{ k}\Omega$	
					47	7 70		$C_{\text{ext}} = 0 \text{ pF},$	
Output pulse			Ω or $\overline{\Omega}$					$R_{\text{ext}} = 2 \text{ k}\Omega$	
width			600	670	670 750	750	$C_{\text{ext}} = 100 \text{ pF},$		
					0.0			$R_{\text{ext}} = 10 \text{ k}\Omega$	
				6	6.7	.7 7.5	5 ms	$C_{\text{ext}} = 1 \mu\text{F},$	
				0.7	7.0	7.5	$R_{\text{ext}} = 10 \text{ k}\Omega$		

Caution in use

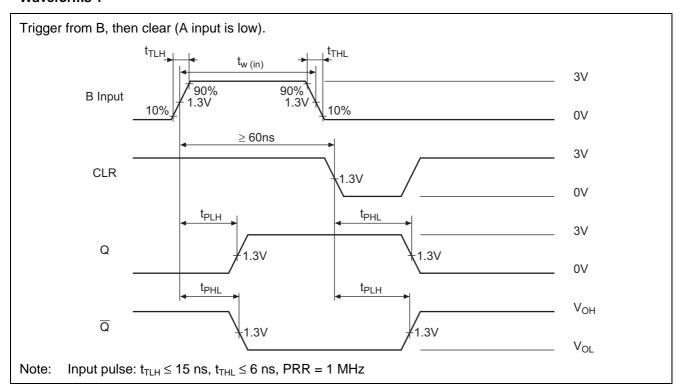
In order to prevent any malfunctions due to noise, connect a high frequency performance capacitor between Vcc and GND, and keep the wiring between the External components and Cext, Rext/Cext pins as short as possible.

Testing Method

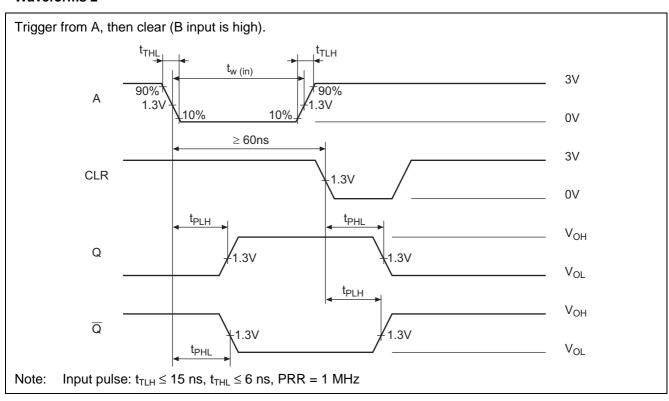
Test Circuit



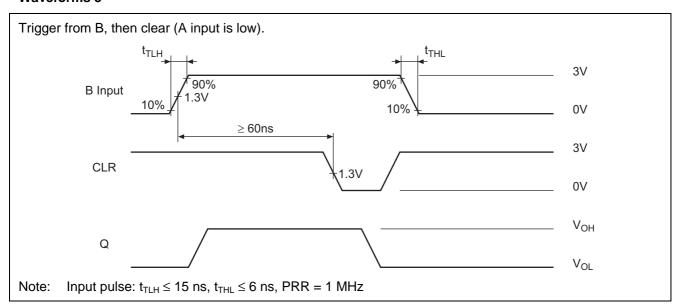
Waveforms 1



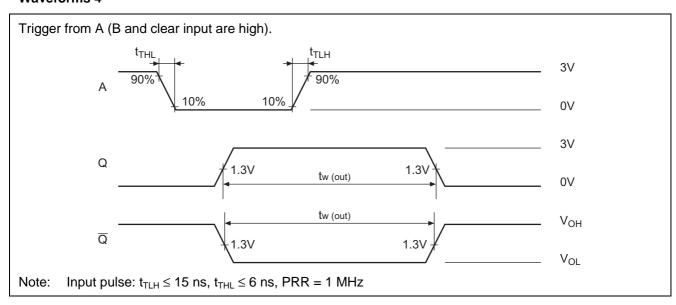
Waveforms 2



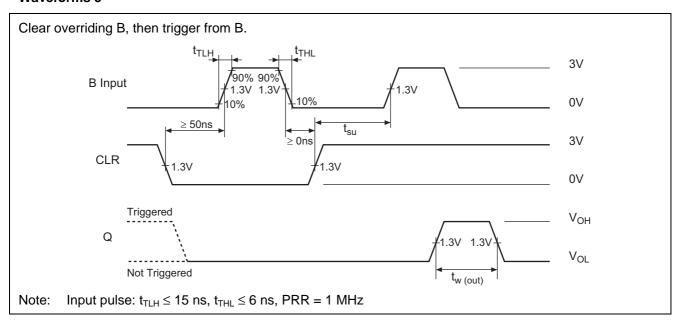
Waveforms 3



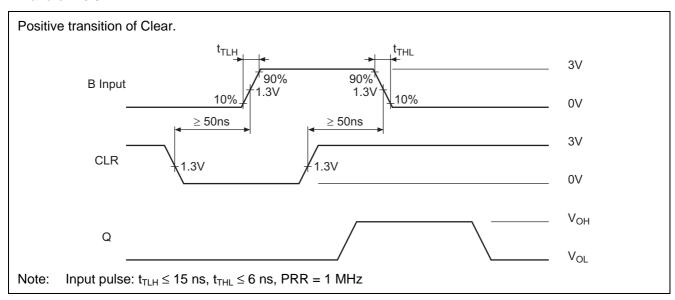
Waveforms 4



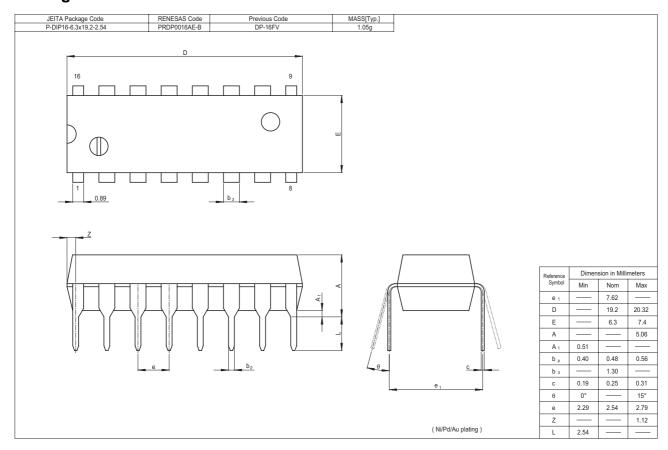
Waveforms 5

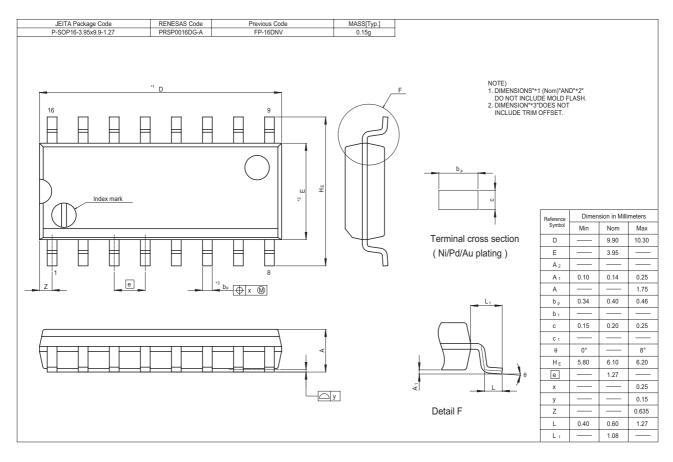


Waveforms 6



Package Dimensions





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